Ordered Nanopillar Structured Electrodes for Depleted Bulk Heterojunction Colloidal Quantum Dot Solar Cells


Colloidal quantum dots (CQDs) have shown great promise in recent years as the active material[1] in third generation photovoltaic devices.[2] In particular, the development of the depleted-heterojunction solar cell[3] has enabled power conversion efficiencies (η) to reach 6%.[4] Despite progress in performance, there still exists a compromise between the absorption of light (where films approaching 1 μm are required to absorb all incident above-bandgap photons[5]) and the extraction of current (where a diffusion length on the order of 10 nm is characteristic of CQD films[6] and depletion is typically limited to 100–200 nm[3]).

Materials and device architecture can play an important role in breaking this compromise. Recent reports have demonstrated performance enhancements through landscaping the energetic profile of the quantum dot film through the deployment of a quantum funnel[7] as well as the geometric profile through a textured porous electrode.[8] This second method allows for collection of charge carriers that would otherwise recombine within the quasi-neutral region if a planar geometry were employed. This device, known as a depleted bulk heterojunction (DBH), is the CQD analogue of bulk heterojunctions widely deployed, to beneficial effect, in organic photovoltaics.[9] The DBH has been implemented both with ZnO nanowires[10] and large TiO2 nanoparticles[8] as the electron-accepting template into which CQDs are deposited. A three-dimensionally-configured depletion region allows the incorporation of more CQD material for more complete light absorption while maintaining efficient charge collection.[8]

To date, disordered structured electrodes have been employed, such as those based on polycrystalline nanoparticle titania. This produces both voids and islands, compromising the advantages of the DBH strategy.

Here we present a novel, ordered structured electrode and deploy it in the realization of infrared-bandgap depleted-heterojunction CQD solar cells. In view of their size-tunability and infrared bandgap, we employ PbS CQDs. We provide titania nanopillars, having a defined spacing, height, and aspect ratio, that lead to enhanced charge collection. We employ a transfer molding technique that enables large areas of uniform topography defined via a master template.[11] The nanopillars are arranged in a hexagonal pattern wherein each nanopillar is equidistant from its nearest neighbours at a peak-to-peak distance of approximately 275 nm as seen in Figure 1.

Figure 1. SEM images of a) top and b) angled side views of titania nanopillars on FTO-coated glass substrates. The hexagonal orientation of the nanopillar array results in sets of equilateral triangles ensuring –275 nm spacing between nearest neighbours. The scale bars are 500 nm.
We optimized the nanopillar spacing based on measurements indicating a ∼150–200 nm depletion region in the best CQD films reported to date.\(^3\) To collect photogenerated carriers efficiently, the distance between adjacent nanopillars must follow Equation 1:

\[
d_{np-np} \approx 2 \cdot (W_{CQD} + L)
\]

where \(d_{np-np}\) is the distance between adjacent nanopillars, \(W_{CQD}\) is the portion of the depletion width residing in the CQD film and \(L\) is the diffusion length of minority carriers (i.e. electrons) in the CQD film. By spacing the nanopillars at 275 nm, Equation 1 is satisfied, ensuring that all photogenerated electrons will be generated in or very near to a depletion region. \(d_{np-np}\) is an upper bound on collection length; it is desirable to array nanopillars at or near this spacing to maximize the volume fill fraction of the light-absorbing CQDs.

CQDs were deposited in a layer-by-layer fashion until a desired thickness was reached. This thickness, for such a three-dimensional bulk heterojunction, must be slightly greater than the height of the nanopillars themselves to avoid direct contact between the top ohmic contact and the TiO\(_2\). MoO\(_3\) followed by gold/silver was used to ensure an ohmic characteristic.\(^12,13\) We depict this design and its realization in Figures 2a and 2b.

Figures 3a and 3b show cross-sectional TEM images of the fabricated planar and nanopillar devices, demonstrating the bicontinuous nature of the CQD/TiO\(_2\) interface. In Figure 3b, the thin layer of CQDs separating the tops of the TiO\(_2\) nanopillars from the MoO\(_3\)/Au/Ag contacts is evident. Also visible is a thick planar layer of TiO\(_2\) nanograins beneath the CQD layer arising from the use of a titania n-butoxide based sol-gel approach.\(^14\) The titania layer prepared using an acetylacetone chelated organotitanate. n-Butyl polytitanate (Tyzor BTP, DuPont) was reacted with acetylacetone to synthesize the chelated titanate. The solution was diluted with propylene glycol propyl ether (PGPE). The organotitanate solution was spin-coated on clean FTO substrates and subsequently baked at 450 °C for 2 hours to crystallize the titane. This gives a flat anatase titania layer on FTO which contains polycrystalline
titania of approximately 10 nm grain size as seen in Figures 3a and 3b.\textsuperscript{[15]}

Figures 4a shows the forward (i.e., open-circuit (OC) to short-circuit (SC), black curves) and reverse (i.e., SC to OC, grey curves) current density vs. voltage ($J$–$V$) performance of the planar and nanopillar samples. We provide external quantum efficiency and absorption spectra for both planar and nanopillar samples in Figure 4b.

The nanopillar device exhibits a much higher open-circuit voltage, $V_{\text{OC}}$, than both the planar control and the previously published depleted bulk heterojunction results.\textsuperscript{[8,10]} Since traps – both interfacial and in the CQD film bulk - can lead to Fermi level pinning,\textsuperscript{[16]} they constrain the $V_{\text{OC}}$ attainable in the device. Since the CQD/TiO$_2$ interface has a larger surface area in the nanopillar case compared to the planar, the fact that nanopillars achieve a notably higher $V_{\text{OC}}$ indicates that traps in the bulk of the CQD films are the performance-limiting mechanism\textsuperscript{[17]} in these devices, instead of titania-CQD interfacial traps. Charge collection by nanopillars competes successfully against capture of photocarriers to traps in the quantum dot film, a fact that helps both $V_{\text{OC}}$ and short-circuit current density, $J_{\text{SC}}$. Very low hysteresis in the nanopillar sample further confirms that collection wins over trapping\textsuperscript{[18,19]}

We turned to self-consistent two-dimensional optoelectronic modelling to explore systematically the conditions to achieve a performance enhancement using the structured electrode. Figures 5a and 5b illustrate optoelectronic modelling results for the electric field at the operating voltage (i.e. the maximum power point) for the case of a planar versus nanopillar architecture. In the nanopillar case, the electric field is stronger in the volume surrounding the nanopillars, thereby increasing the volume from which photogenerated carriers can be extracted. The model posits traps of depth 0.25 eV below the conduction band edge\textsuperscript{[20]} that serve to limit the separation of the quasi-Fermi levels under solar illumination as well as impede transport of free carriers.\textsuperscript{[21]} To explore further the causes of enhanced carrier extraction, we inspected trap occupation probabilities (Figures 5c and 5d) as well as Shockley-Reed-Hall (SRH) recombination rates (Figures 5e and 5f) for the planar and nanopillar cases. The nanopillars enhance carrier extraction by ensuring that more photocarriers see efficient field-driven transport that overcomes recombination. Similar nanopillar-enabled suppression of SRH recombination has been seen previously in electro-optical models of organic nanopillar photovoltaics.\textsuperscript{[22]} Electro-optical modelling parameters are outlined in SOM 1.

Table 1 summarizes the figures of merit extracted from the $J$–$V$ curves of Figure 4a. Static $V_{\text{OC}}$, $J_{\text{SC}}$ and maximum power point measurements are also included that confirm the $\eta = 5.6\%$ measured during the $J$–$V$ scan. The static $J_{\text{SC}}$ value of 19 mA/cm$^2$ achieved by the nanopillar samples is similar to the $J_{\text{SC}}$ previously reported using infiltration of colloidal quantum dots into much thicker TiO$_2$ nanoparticle layers.\textsuperscript{[8]} The nanopillar sample, unlike the large TiO$_2$ nanoparticle sample, is limited in the vertical direction by the height of the nanopillars. Because of this limitation, the 320 nm film absorbs only 46% of incident light at the exciton wavelength (Figure 4b), whereas the much taller TiO$_2$ nanoparticle device showed $>60\%$ absorption at the exciton wavelength. Despite the reduction in long-wavelength absorption, the nanopillar device exhibits similar extracted current and overall enhanced power conversion efficiency.

While CQD materials continue to improve, leading to further progress in optical and electrical properties, solar cell device architecture remains critical in achieving high efficiencies. By tailoring the bulk heterojunction concept to the transport characteristics of CQD films, we enhanced charge collection efficiency in three dimensions. Using conveniently
available patterning technologies, we showed that, with this optimal template design, power conversion efficiencies of 5.6% can be achieved using available PbS CQD films—efficiencies that exceed those achieved using planar electrode approaches.

Table 1. Figures of merit for planar and nanopillar devices. Static values were recorded for \( V_{OC} \), \( J_{SC} \) and the maximum power point and are reported along with voltage sweeps from open-circuit to short-circuit as well as from short-circuit to open-circuit.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Units</th>
<th>Planar</th>
<th>Nanopillar</th>
</tr>
</thead>
<tbody>
<tr>
<td>Static</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>( V_{OC} )</td>
<td>mV</td>
<td>520</td>
<td>570</td>
</tr>
<tr>
<td>( J_{SC} )</td>
<td>mA/cm²</td>
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<td>19.0</td>
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<tr>
<td>( \eta )</td>
<td>%</td>
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<tr>
<td>Open-Circuit → ( V_{OC} )</td>
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<td>500</td>
<td>570</td>
</tr>
<tr>
<td>( J_{SC} )</td>
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<td>19.7</td>
</tr>
<tr>
<td>( FF )</td>
<td>%</td>
<td>49</td>
<td>49</td>
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<tr>
<td>( \eta )</td>
<td>%</td>
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<td>5.5</td>
</tr>
<tr>
<td>( R_s )</td>
<td>Ω cm²</td>
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<td>20.1</td>
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<tr>
<td>( FF )</td>
<td>%</td>
<td>41</td>
<td>49</td>
</tr>
<tr>
<td>( \eta )</td>
<td>%</td>
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<tr>
<td>( R_s )</td>
<td>Ω cm²</td>
<td>11.9</td>
<td>6.2</td>
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**Experimental Section**

**Titania Nanopillar Fabrication:** Titania structure was prepared using an acrylatedene chelated organotitanate. n-Butyl polystyrene (Tyzor BTP, DuPont) was reacted with acetylacetone to synthesize the chelated titanate. The solution was diluted with propylene glycol propyl ether (PGPE). The organotitanate solution was spin-coated on clean FTO substrates and subsequently baked at 450 °C for 2 h to crystallize the titanate. This gives a flat anatase titanayer on FTO which contains polycrystalline titania of approximately 10 nm in grain size. Titania nanopillars were fabricated using a transfer molding technique using a water soluble polymer template. The polymer template was prepared by molding a poly(vinyl alcohol) (PVA) on a silicon master which contains pillars of ~135 nm in diameter at half-height, 750 nm tall and a 275 nm center-to-center spacing. The silicon master was prepared using conventional optical lithography and plasma etching. Acetic acid was added to the PGPE solution of the organotitanate and the solution was spin-coated onto a PVA daughter template at 2000 rpm for 45 s. The sample was heated to 80 °C for 10 s before transfer onto the titanate coated FTO substrates. The sample was exposed to 245 nm UV illumination at room temperature for 30 min. Dissolution of the PVA template was carried out at 42–85 °C (pH 4–7) for 25 min. The film was rinsed with water then dried with ethanol and nitrogen before the calcination of titania was carried out by baking at 450 °C for 2 h (ramp up at 5 °C/min).

**CQD Synthesis:** PbS colloidal quantum dots were synthesized using a variation on a literature method\(^{(2)}\) consistent with our previous CQD solar cells.\(^{(1)}\)

**Device Fabrication:** CQD films were prepared on nanopillar electrodes by multilayer spincoating of 37.5 mg mL\(^{-1}\) solution in octane under ambient conditions. Each layer was deposited at 2500 rpm and treated briefly with 1% 3-mercaptopropionic acid in methanol also spin cast at 2500 rpm; each layer was then rinsed with methanol and octane while spinning at 2500 rpm. The device was then transferred to a glovebox with N\(_2\) atmosphere and left overnight. Contacts consisting of 10 nm of MoO\(_3\), topped with 50 nm of gold and 80 nm of silver were deposited by thermal and electron beam evaporation at a rate of 0.2 (thermal), 0.4 (electron beam) and 1 Å/s (thermal), respectively, at a pressure of <1 × 10\(^{-6}\) mbar. Contact sizes were 0.061 cm\(^2\).

**J–V Characterization:** J–V data was measured using a Keithley 2400 source-meter under ambient conditions. The solar spectrum at AM1.5 was simulated to within class A specifications (less than 25% spectral mismatch) with a Xe lamp and filters (ScienceTech) with measured intensity at 100.4 mW cm\(^{-2}\). The source intensity was estimated to be ±3%.

**Electron Microscopy:** SEM was performed on a Hitachi S-4700 at 5-4700 at 3 kV. For TEM analysis, ~50 nm thick cross sectional slice containing nanopillars was prepared using focus ion beam (FIB). Specimen’s surface was coated with carbon, e-beam and ion beam platinum prior to TEM sample preparation for protection. Conventional TEM and High Angle Annular Dark field (HAADF) STEM images were acquired using a JEOL 2010F.
Absorption Measurements: Absorption spectroscopy was carried out using a Cary 500 UV-vis-IR Scan photospectrometer with an attached integrating sphere.

Supporting Information
Supporting Information is available from the Wiley Online Library or from the author.

Acknowledgements
This publication is based on work in part supported by Award No. KUS-11-009-21, made by King Abdullah University of Science and Technology (KAUST), the Ontario Research Fund Research in Excellence Program and the Natural Sciences and Engineering Research Council (NSERC) of Canada. We thank Angstrom Engineering and Innovative Technologies for useful discussions regarding material deposition methods and control of glovebox environment, respectively. I.J.K., D.Z., A.H.I. and R.D. acknowledge the financial support through the Ontario Graduate Fellowship, respectively. H-C. K. thanks Eugene Delenia Graduate Scholarship in Science and Technology and the MITACS Scholarship, the NSERC CGS D Scholarship, the Queen Elizabeth II Graduate Scholarship and the Natural Sciences and Engineering Research Council (NSERC) of Canada. We thank Angstrom Engineering and Innovative Technologies for TEM sample preparation. He also acknowledges the financial support through the Ontario Graduate Fellowship, respectively. H-C. K. thanks Eugene Delenia Graduate Scholarship in Science and Technology and the MITACS Scholarship, the NSERC CGS D Scholarship, the Queen Elizabeth II Graduate Scholarship and the Natural Sciences and Engineering Research Council (NSERC) of Canada. We thank Angstrom Engineering and Innovative Technologies for TEM sample preparation.

Received: December 18, 2011
Revised: February 3, 2012
Published online: March 30, 2012